



**TIP140/141/142
TIP145/146/147**

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

- TIP141, TIP142, TIP145 AND TIP147 ARE STMicroelectronics PREFERRED SALES TYPES
- COMPLEMENTARY PNP - NPN DEVICES
- MONOLITHIC DARLINGTON CONFIGURATION
- INTEGRATED ANTIPARALLEL COLLECTOR-EMITTER DIODE

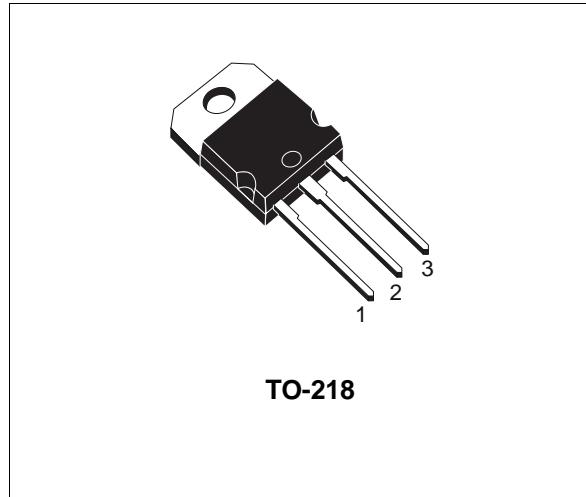
APPLICATIONS

- LINEAR AND SWITCHING INDUSTRIAL EQUIPMENT

DESCRIPTION

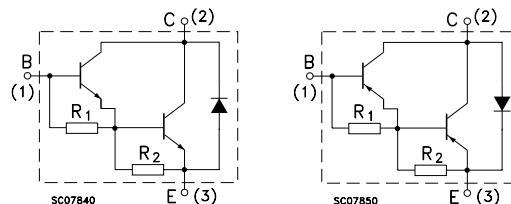
The TIP140, TIP141 and TIP142 are silicon Epitaxial-Base NPN power transistors in monolithic Darlington configuration, mounted in TO-218 plastic package. They are intended for use in power linear and switching applications.

The complementary PNP types are TIP145, TIP146 and TIP147 respectively.



TO-218

INTERNAL SCHEMATIC DIAGRAM



R₁ Typ. = 5 kΩ

R₂ Typ. = 150 Ω

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value				Unit
		NPN	TIP140	TIP141	TIP142	
		PNP	TIP145	TIP146	TIP147	
V _{CBO}	Collector-Base Voltage ($I_E = 0$)		60	80	100	V
V _{CEO}	Collector-Emitter Voltage ($I_B = 0$)		60	80	100	V
V _{EBO}	Emitter-Base Voltage ($I_C = 0$)			5		V
I _C	Collector Current			10		A
I _{CM}	Collector Peak Current			20		A
I _B	Base Current			0.5		A
P _{tot}	Total Dissipation at $T_{case} \leq 25^\circ C$			125		W
T _{stg}	Storage Temperature			-65 to 150		°C
T _j	Max. Operating Junction Temperature			150		°C

For PNP types voltage and current values are negative.

TIP140 / TIP141 / TIP142 / TIP145 / TIP146 / TIP147

THERMAL DATA

$R_{thj-case}$	Thermal Resistance Junction-case	Max	1	$^{\circ}\text{C/W}$
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ELECTRICAL CHARACTERISTICS ($T_{case} = 25 \ ^{\circ}\text{C}$ unless otherwise specified)

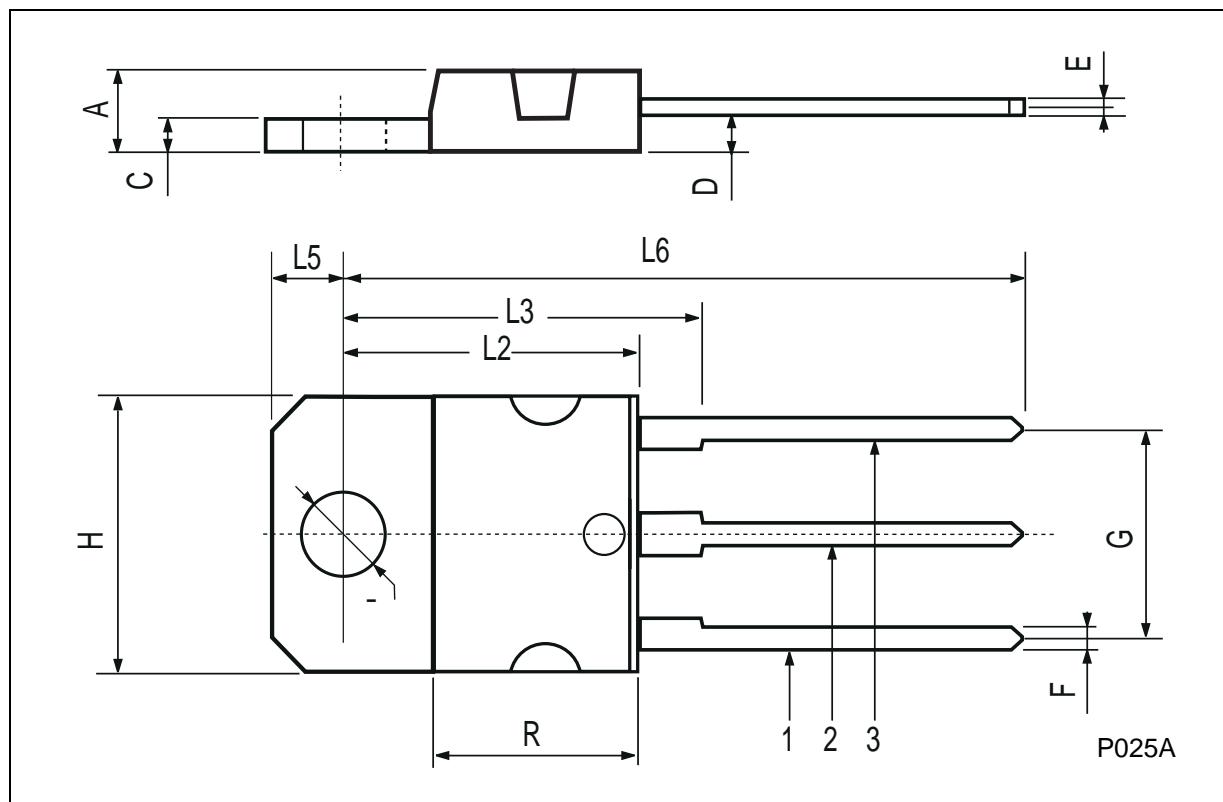
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current ($I_E = 0$)	for TIP140/145 $V_{CB} = 60 \text{ V}$ for TIP141/146 $V_{CB} = 80 \text{ V}$ for TIP142/147 $V_{CB} = 100 \text{ V}$			1 1 1	mA mA mA
I_{CEO}	Collector Cut-off Current ($I_B = 0$)	for TIP140/145 $V_{CE} = 30 \text{ V}$ for TIP141/146 $V_{CE} = 40 \text{ V}$ for TIP142/147 $V_{CE} = 50 \text{ V}$			2 2 2	mA mA mA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 5 \text{ V}$			2	mA
$V_{CEO(sus)}^*$	Collector-Emitter Sustaining Voltage ($I_B = 0$)	$I_C = 30 \text{ mA}$ for TIP140/145 for TIP141/146 for TIP142/147	60 80 100			V V V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = 5 \text{ A}$ $I_B = 10 \text{ mA}$ $I_C = 10 \text{ A}$ $I_B = 40 \text{ mA}$			2 3	V V
$V_{BE(on)}^*$	Base-Emitter Voltage	$I_C = 10 \text{ A}$ $V_{CE} = 4 \text{ V}$			3	V
h_{FE}^*	DC Current Gain	$I_C = 5 \text{ A}$ $V_{CE} = 4 \text{ V}$ $I_C = 10 \text{ A}$ $V_{CE} = 4 \text{ V}$	1000 500			
t_{on} t_{off}	RESISTIVE LOAD Turn-on Time Turn-off Time	$I_C = 10 \text{ A}$ $I_{B1} = 40 \text{ mA}$ $I_{B2} = -40 \text{ mA}$ $R_L = 3 \Omega$		0.9 4		μs μs

For PNP types voltage and current values are negative.

* Pulsed: Pulse duration = 300 μs , duty cycle 1.5 %

TO-218 (SOT-93) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.7		4.9	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.5			0.098	
E	0.5		0.78	0.019		0.030
F	1.1		1.3	0.043		0.051
G	10.8		11.1	0.425		0.437
H	14.7		15.2	0.578		0.598
L2	-		16.2	-		0.637
L3		18			0.708	
L5	3.95		4.15	0.155		0.163
L6		31			1.220	
R	-		12.2	-		0.480
Ø	4		4.1	0.157		0.161



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